MOSPEC

MURD860

SWITCH MODE POWER RECTIFIERS
DPAK SURFACE MOUNT POWER PACKAGE

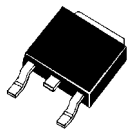
Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

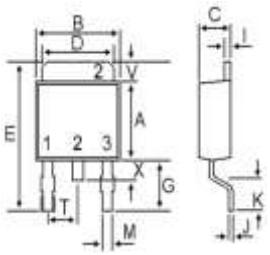
- High Surge Capacity
- Low Power Loss, High efficiency
- High Operating Junction Temperature
- Low Stored Charge Majority Carrier Conduction
- Low Forward Voltage , High Current Capability
- High-Switching Speed Recovery Time
- Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- Pb free
- In compliance with EU RoHs directives

ULTRA FAST RECTIFIERS

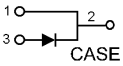
8 AMPERES
600 VOLTS



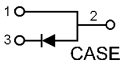
TO-252AA



DIM	MILLIMETERS	
	MIN	MAX
A	5.97	6.22
B	6.30	6.75
C	2.18	2.40
D	4.95	5.46
E	9.40	10.41
G	2.75	3.20
I	0.46	0.89
J	0.46	0.61
K	1.40	1.78
M	0.64	0.89
T	2.28	2.30
V	0.89	1.27
X	---	1.05



Case Positive



Case Negative Suffix "R"

MAXIMUM RATINGS

Characteristic	Symbol	MURD860	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	420	V
Average Rectifier Forward Current	$I_{F(AV)}$	8	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	8	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I_{FSM}	100	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	℃

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage (I_F =8 Amp T_C = 25℃) (I_F =8 Amp T_C = 125℃)	V_F	--- ---	1.12 0.92	1.6 ---	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	--- ---	0.02 5	10 ---	uA
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	T_{rr}	---	26	35	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P		90		pF

FIG-1 TYPICAL FORWARD CHARACTERISTICS

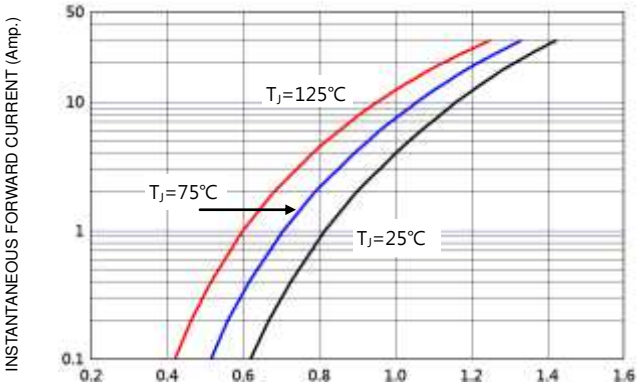


FIG-3 TYPICAL FORWARD CURRENT DERATING CURVE

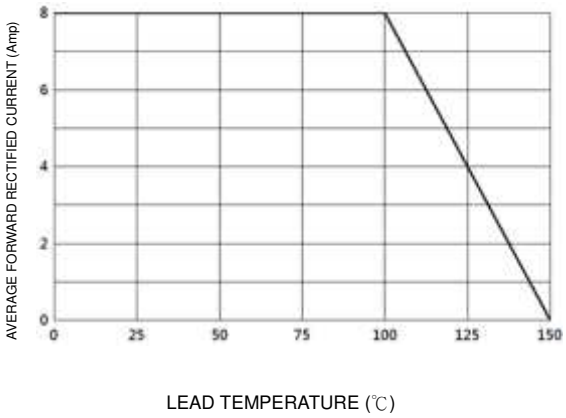


FIG-2 TYPICAL REVERSE CHARACTERISTICS

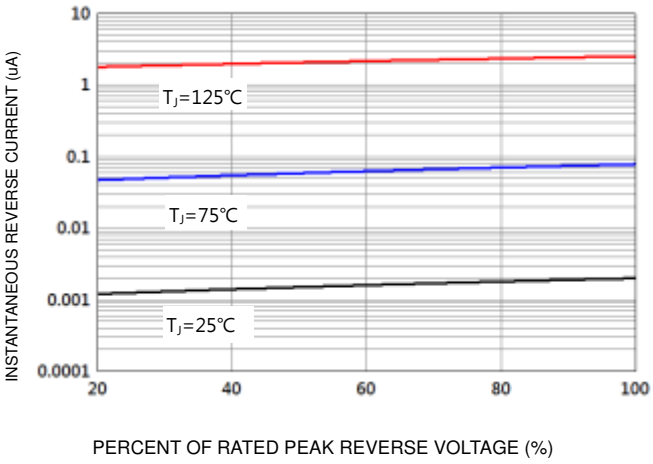
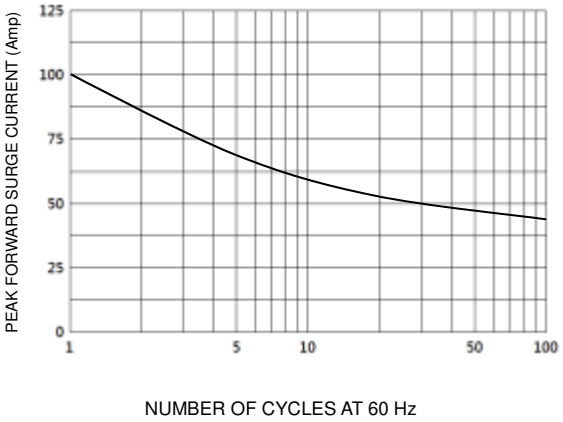
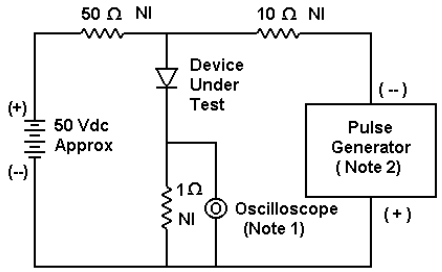
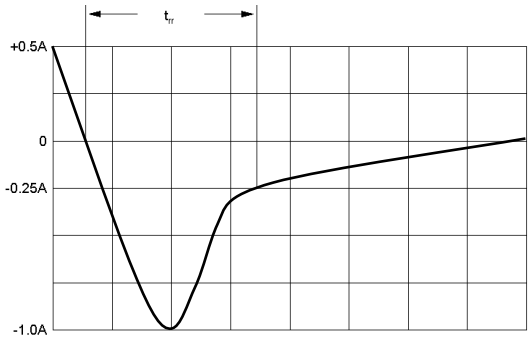


FIG-4 TYPICAL PEAK FORWARD SURGE CURRENT





Notes:
1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF
2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

FIG-5 Reverse Recovery Time Characteristic and Test Circuit Diagram

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